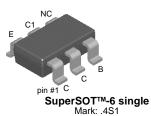


SEMICONDUCTOR®

# **FMBS5401**

## **PNP General Purpose Amplifier**

• This device is designed as a general purpose amplifier and switch for applications requiring high voltage.



# **PNP Epitaxial Silicon Transistor**

Symbol	Parameter	Value	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	-150	V	
V <sub>CBO</sub>	Collector-Base Voltage	-160	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V	
I <sub>C</sub>	Collector Current - Continuous	-600	mA	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ 150	°C	

## Absolute Maximum Ratings\* T<sub>a</sub>=25°C unless otherwise noted

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Notes:

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics Ta=25°C unless otherwise noted

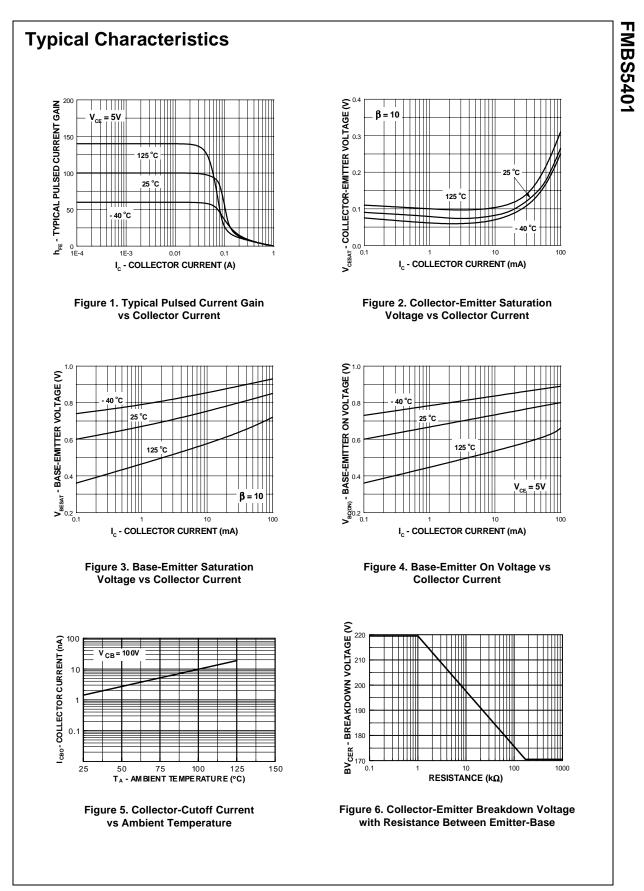
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charac	teristics				
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage *	$I_{\rm C} = -1.0 {\rm mA}, I_{\rm B} = 0$	-150		V
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = -100 \mu A, I_{E} = 0$	-160		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = -10\mu A, I_{C} = 0$	-5.0		V
I <sub>CBO</sub>	Collector Cutoff Current	$V_{CB} = -120V, I_E = 0$ $V_{CB} = -120V, I_E = 0, T_a = 100^{\circ}C$		-50 -50	nA μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -3.0V, I <sub>C</sub> =0		-50	nA
On Charac	teristics *				
h <sub>FE</sub>	DC Current Gain	$I_{C} = -1.0mA, V_{CE} = -5.0V$ $I_{C} = -10mA, V_{CE} = -5.0V$ $I_{C} = -50mA, V_{CE} = -5.0V$	50 60 50	240	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_{C} = -10mA$ , $I_{B} = -1.0mA$ $I_{C} = -50mA$ , $I_{B} = -5.0mA$		-0.2 -0.5	V V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> = -1.0mA I <sub>C</sub> = -50mA, I <sub>B</sub> = -5.0mA		-1.0 -1.0	V V
Small Sign	al Characterics				
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -10V, f = 100MHz	100	300	MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB} = -10V, I_E = 0, f = 1MHz$		6.0	pF
N <sub>F</sub>	Noise Figure	$I_{C}$ = -250μA, V <sub>CE</sub> = -5.0V, R <sub>S</sub> = 1.0KΩ f = 10Hz to 15.7KHz		8.0	dB

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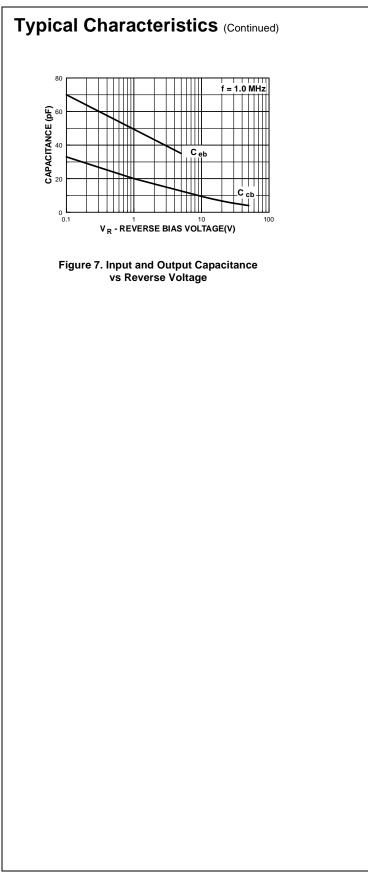
FMBS5401

Total Device Dissipation * 700 mW   Thermal Resistance, Junction to Ambient, total 180 °C/W	Total Device Dissipation * 700 mW   Thermal Resistance, Junction to Ambient, total 180 °C/W	Total Device Dissipation * 700 mW
Thermal Resistance, Junction to Ambient, total 180 °C/W   ounted on a 1 in 2 pad of 2 oz coppe 0 0 0	Thermal Resistance, Junction to Ambient, total 180 °C/W   nounted on a 1 in 2 pad of 2 oz coppe 0	Thermal Resistance, Junction to Ambient, total     180     °C/W       mounted on a 1 in 2 pad of 2 oz coppe     °C/W     °C/W
ounted on a 1 in 2 pad of 2 oz coppe	nounted on a 1 in 2 pad of 2 oz coppe	mounted on a 1 in 2 pad of 2 oz coppe

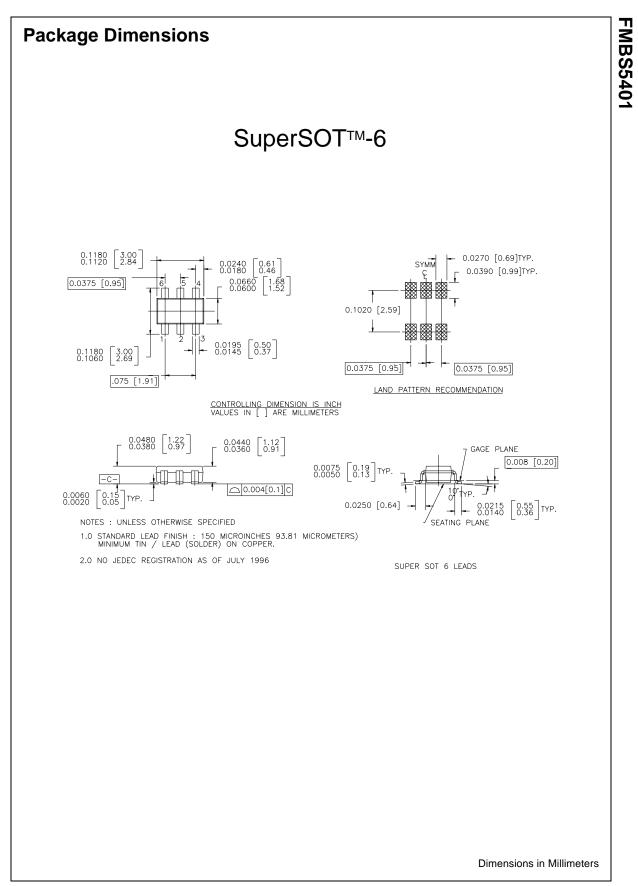
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#### **Definition of Terms**

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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